

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized applications, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an ad experson



March 2015

P-Channel 1.8V Specified PowerTrench® MOSFET

Features

■ -6.7 A, -12 V. $R_{DS(ON)} = 28 \text{ m}\Omega @ V_{GS} = -4.5 \text{ V}$

- $R_{DS(ON)} = 41 \text{ m}\Omega @ V_{GS} = -2.5 \text{ V}$ $R_{DS(ON)} = 90 \text{ m}\Omega @ V_{GS} = -1.8 \text{ V}$
- Fast switching speed
- High performance trench technology for extremely low R_{DS(ON)}
- High power and current handling capability

Applications

DC/DC converter

General Description

This P-Channel 1.8V Specified MOSFET uses Fairchild's advanced low voltage PowerTrench process. It has been optimized for battery power management.





Absolute Maximum Ratings $T_A=25^{\circ}C$ unless otherwise noted

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-Source Voltage		-12	V	
V _{GSS}	Gate-Source Voltage		±8	V	
ID	Drain Current – Continuous	(Note 3)	-6.7	A	
	– Pulsed	(Note 1a)	-54		
P _D	Power Dissipation for Single Operation	(Note 1)	52	W	
		(Note 1a)	3.8		
		(Note 1b)	1.6		
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +175	°C	
Thermal Cha	aracteristics	ŀ			
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	2.9	°C/W	
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	40	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1b)	96	°C/W	

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
FDD306P	FDD306P	13"	16mm	2500 units

FDD306P
P-Channel
1.8V S
pecified
-Channel 1.8V Specified PowerTrench [®] M(
MOSFET

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Charac	teristics		!			
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = -250 \mu\text{A}$	-12			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		-0.6		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μA
I _{GSSF}	Gate-Body Leakage	$V_{GS} = \pm 8V$, $V_{DS} = 0V$			±100	nA
On Charac	teristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	-0.4	-0.5	-1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		2.2		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS}=-4.5 \text{ V}, \text{ I}_{D}=-6.7 \text{ A} \\ V_{GS}=-2.5 \text{ V}, \text{ I}_{D}=-6.1 \text{ A} \\ V_{GS}=-1.8 \text{ V}, \text{ I}_{D}=-4.8 \text{ A} \\ V_{GS}=-4.5 \text{ V}, \text{ I}_{D}=-6.7 \text{ A}, \text{ T}_{J}=125^{\circ}\text{C} \end{array} $		21 29 42 25	28 41 90	mΩ
I _{D(on)}	On-State Drain Current	$V_{GS} = -4.5 \text{ V}, V_{DS} = -5 \text{ V}$	-45			Α
9 _{FS}	Forward Transconductance	$V_{DS} = -5 \text{ V}, \text{ I}_{D} = -6.7 \text{ A}$		22		S
Dynamic C	characteristics	•			•	
C _{iss}	Input Capacitance	$V_{DS} = -6 V, V_{GS} = 0 V,$		1290		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		590		pF
C _{rss}	Reverse Transfer Capacitance			430		pF
R _G	Gate Resistance	V _{GS} = 15 mV, f = 1.0 MHz		4.2		Ω
Switching	Characteristics (Note 2)					
t _{d(on)}	Turn–On Delay Time	$V_{DD} = -6 V, I_D = -1 A,$		16	29	ns
t _r	Turn–On Rise Time	$V_{GS} = -4.5$ V, $R_{GEN} = 6 \Omega$		8	16	ns
t _{d(off)}	Turn–Off Delay Time			34	54	ns
t _f	Turn–Off Fall Time			41	65	ns
Qg	Total Gate Charge	$V_{DS} = -6V, I_D = -6.7 A,$		15	21	nC
Q _{gs}	Gate–Source Charge	$V_{GS} = -4.5 V$		2.0		nC
Q _{gd}	Gate-Drain Charge			4.4		nC
Drain–Sou	rce Diode Characteristics and Maximum Ra	atings				
I _S	Maximum Continuous Drain-Source Diode Fo	orward Current			-3.2	A
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V, I_S = -3.2 A$ (Note 2)		-0.8	-1.2	V
Trr	Diode Reverse Recovery Time	IF = -6.7 A, diF/dt = 100 A/µs (Note 3)		37		ns
lrm	Diode Reverse Recovery Current			0.9		A
Qrr	Diode Reverse Recovery Charge			17		nC

Notes: 1. $R_{\theta,JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta,JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. a) $R_{\theta JA} = 40^{\circ}C/W$ when mounted on a 1in² pad of 2 oz copper b) $R_{\theta,JA} = 96^{\circ}C/W$ when mounted on a minimum pad.

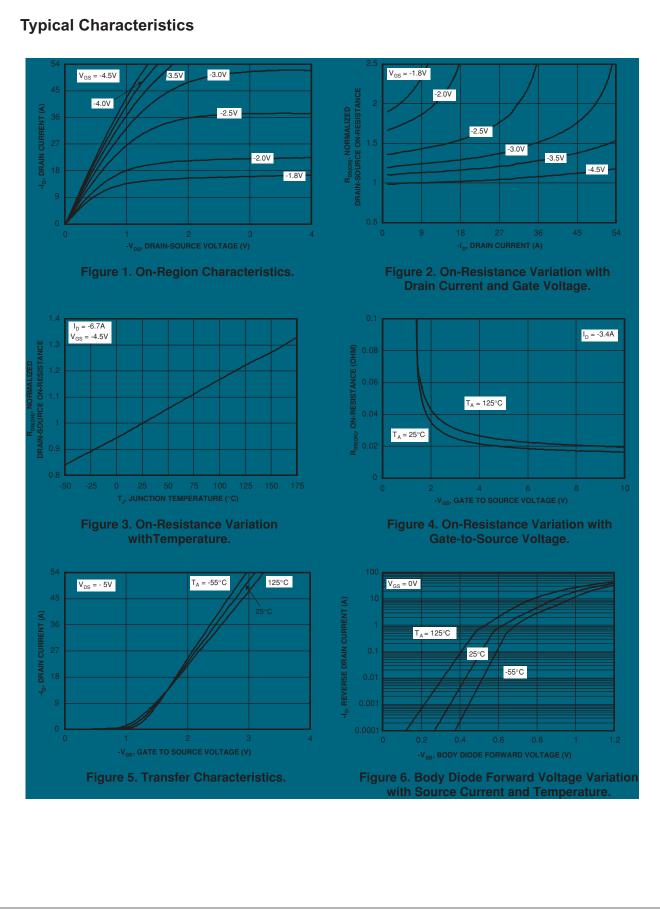


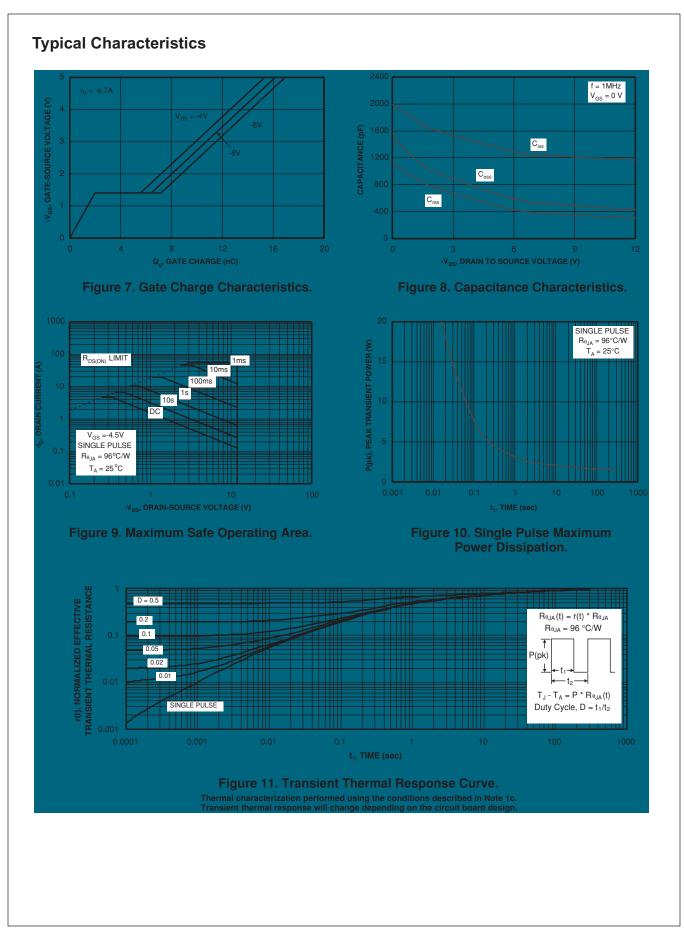
Scale 1 : 1 on letter size paper

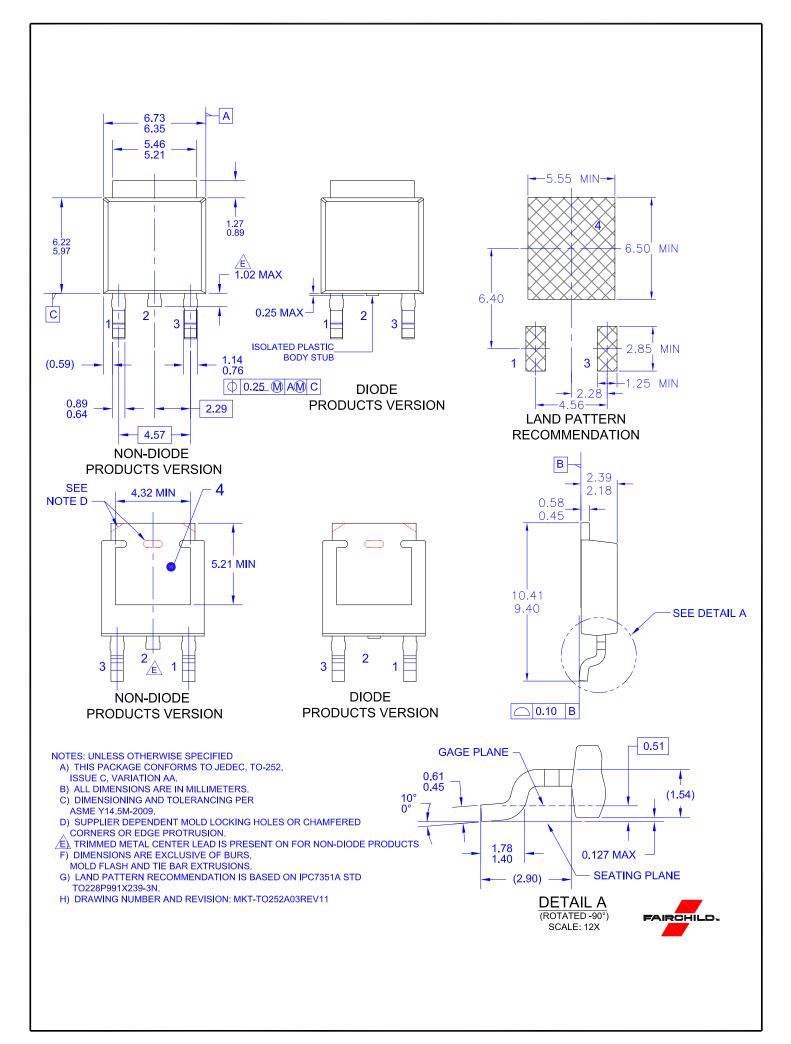
2. Pulse Test: Pulse Width < 300 μ s, Duty Cycle < 2.0%

 $\sqrt{\frac{P_D}{R_{DS(ON)}}}$ where P_D is maximum power dissipation at T_C = 25°C and R_{DS(on)} is at T_{J(max)} and V_{GS} = 10V. 3. Maximum current is calculated as:

4. Starting T_J = 25°C, L = 3 mH, I_{AS} = -4 A, V_{GS} = -10 V, V_{DD} = -12 V.







ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative